# NSN 5961-00-583-1975

Transistor - Page 1 of 1



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# Inclosure Material:

Glass and metal

# **Overall Length:**

0.435 inches

# **Overall Height:**

0.315 inches

# **Overall Width:**

0.250 inches

# Mounting Facility Quantity:

1

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### Mounting Method:

Clip and unthreaded hole

#### Features Provided:

Hermetically sealed case

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open

## **Current Rating Per Characteristic:**

60.00 milliamperes source cutoff current

## Power Rating Per Characteristic:

750.0 milliwatts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

## **Terminal Type And Quantity:**

3 uninsulated wire lead

#### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

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